TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# **TLP731, TLP732**

Office Machine Household Use Equipment Solid State Relay Switching Power Supply

The TOSHIBA TLP731 and TLP732 consist of a photo–transistor optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

TLP732 is no-base internal connection for high-EMI environments.

• Collector-emitter voltage: 55V (min)

• Current transfer ratio: 50% (min)

Rank GB: 100% (min)

- UL recognized: UL1577, file No. E67349
- c-UL recognized: CSA Component Acceptance Service No. 5A
   File No.E67349
- BSI approved: BS EN60065: 2002

Certificate No. 8877 BS EN60950-1: 2002 Certificate No. 8878

- Isolation voltage: 4000 V<sub>rms</sub> (min)
- Option (D4) type

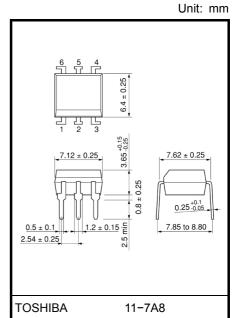
VDE approved: DIN EN 60747-5-2,

Certificate No. 40009302

Maximum operating insulation voltage:  $630 V_{PK}$  Highest permissible over voltage:  $6000 V_{PK}$ 

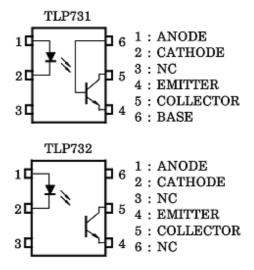
(Note) When a EN 60747-5-2 approved type is needed, please designate the "Option (D4)"

		7.62mm pich	10.16mm pich
		standard type	(LF2) type
•	Creepage distance	: 7.0mm (min)	8.0 mm (min)
	Clearance	: 7.0 mm (min)	8.0 mm (min)
	Insulation thickness	: 0.5 mm (min)	0.5 mm (min)



Weight: 0.35 g (typ.)

### Pin Configurations (top view)



Start of commercial production 1985/02

### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	IF	60	mA
	Forward current derating (Ta ≥ 39°C)	ΔI <sub>F</sub> / °C	-0.7	mA / °C
	Peak forward current (100µs pulse, 100pps)	I <sub>FP</sub>	1	Α
LED	Power dissipation	PD	100	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>D</sub> / °C	-1.0	mW / °C
	Reverse voltage	V <sub>R</sub>	5	V
	Junction temperature	Tj	125	°C
	Collector–emitter voltage	V <sub>CEO</sub>	55	V
	Collector-base voltage (TLP731)	V <sub>CBO</sub>	80	V
	Emitter–collector voltage	V <sub>ECO</sub>	7	V
Detector	Emitter-base voltage (TLP731)	V <sub>EBO</sub>	7	V
Dete	Collector current	IC	50	mA
	Power dissipation	PC	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> / °C	-1.5	mW / °C
	Junction temperature	Tj	125	°C
Storag	e temperature range	T <sub>stg</sub>	-55 to 125	°C
Operat	ting temperature range	T <sub>opr</sub>	-55 to 100	°C
Lead s	Lead soldering temperature (10s) T <sub>sol</sub>		260	°C
Total p	ackage power dissipation	PT	250	mW
Total p	eackage power dissipation derating (Ta ≥ 25°C)	ΔP <sub>T</sub> / °C	-2.5	mW / °C
Isolatio	on voltage (AC, 1minute, R.H. ≤ 60%)	BVS	4000	V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V <sub>CC</sub>	_	5	24	V
Forward current	lF	_	16	25	mA
Collector current	IC	_	1	10	mA
Operating temperature	T <sub>opr</sub>	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



# Individual Electrical Characteristics (Ta = 25°C)

	Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage		$V_{F}$	I <sub>F</sub> = 10mA	1.0	1.15	1.3	V
LED	Reverse current		I <sub>R</sub>	V <sub>R</sub> = 5V	_	_	10	μA
	Capacitance		C <sub>T</sub>	V = 0, f = 1MHz	-	30	_	pF
	Collector–emitter breakdown voltage		V <sub>(BR)CEO</sub>	I <sub>C</sub> = 0.5mA	55	_	1	V
	Emitter–collector breakdown voltage		V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1mA	7	_	1	V
	Collector-base breakdown voltage (7	TLP731)	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 0.1mA	80	_	_	V
Ē	Emitter-base breakdown voltage (TLP731)	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 0.1mA	7	_	_	V	
Detector	Collector dark current		la=-a	V <sub>CE</sub> = 24V	_	10	100	nA
Del	Collector dark current		I <sub>CEO</sub>	V <sub>CE</sub> = 24V, Ta = 85°C	_	2	50	μA
	Collector dark current	TLP731)	I <sub>CER</sub>	$V_{CE}$ = 24V, Ta = 85°C R <sub>BE</sub> = 1M $\Omega$	_	0.5	10	μΑ
	Collector dark current (	TLP731)	I <sub>CBO</sub>	V <sub>CB</sub> = 10V		0.1		nA
	DC forward current gain (	TLP731)	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.5mA		400		_
	Capacitance collector to e	mitter	C <sub>CE</sub>	V = 0, f = 1MHz	_	10	_	pF

# **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	lo / l=	I <sub>F</sub> = 5mA, V <sub>CE</sub> = 5V	50	_	600	%
Current transfer fatto	I <sub>C</sub> / I <sub>F</sub>	Rank GE	100	_	600	70
Saturated CTR	lo/le/ o	I <sub>F</sub> = 1mA, V <sub>CE</sub> = 0.4V	_	60	_	%
Saturated CTK	I <sub>C</sub> / I <sub>F (sat)</sub>	Rank GE	30	_	_	70
Base photo-current (TLP731)	I <sub>PB</sub>	I <sub>F</sub> = 5mA, V <sub>CB</sub> = 5V	_	10	_	μΑ
		I <sub>C</sub> = 2.4mA, I <sub>F</sub> = 8mA	_	_	0.4	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 0.2mA, I <sub>F</sub> = 1mA	_	0.2	_	V
		Rank GE	_	_	0.4	

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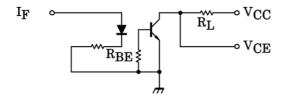
# Isolation Characteristics (Ta = 25°C)

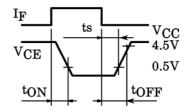
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V <sub>S</sub> = 0, f = 1MHz	_	8.0	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500V, R.H.≦60%	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC, 1 minute	4000	_	_	W
Isolation voltage		AC, 1 second, in oil	_	10000	_	V <sub>rms</sub>
		DC, 1 minute, in oil	_	10000	-	V <sub>dc</sub>

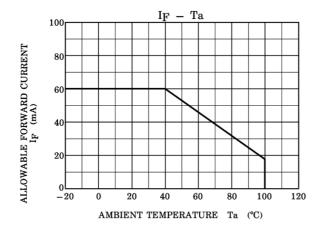
### **Switching Characteristics (Ta = 25°C)**

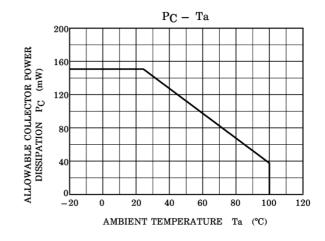
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t <sub>r</sub>		_	2	_	
Fall time	t <sub>f</sub>	V <sub>CC</sub> = 10V, I <sub>C</sub> = 2mA	_	3	_	μs
Turn-on time	t <sub>on</sub>	$R_L = 100\Omega$	_	3	10	
Turn-off time	t <sub>off</sub>		_	3	10	
Turn-on time	t <sub>ON</sub>	D = 4.0k0 (Fig.4)	_	2	_	
Storage time	t <sub>s</sub>	$R_L = 1.9k\Omega$ (Fig.1) $R_{BE} = open$	_	15	_	μs
Turn-off time	t <sub>OFF</sub>	V <sub>CC</sub> = 5V, I <sub>F</sub> = 16mA	_	25	_	
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> = 1.9kΩ (Fig.1) R <sub>BE</sub> = 220kΩ (TLP731) V <sub>CC</sub> = 5V, I <sub>F</sub> = 16mA	_	2	_	
Storage time	ts		_	12	_	μs
Turn-off time	tOFF		_	20	_	

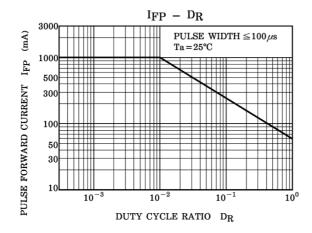
Fig. 1 Switching time test circuit

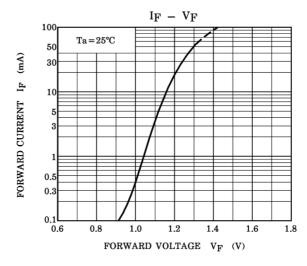


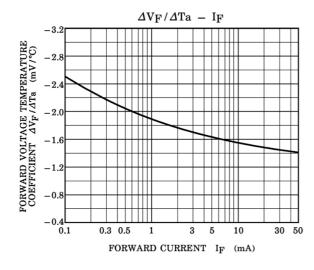


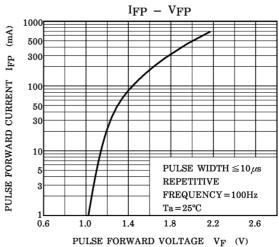


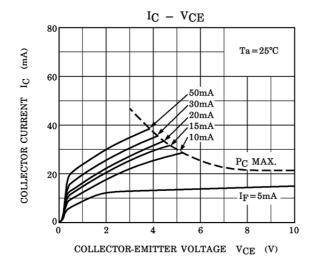


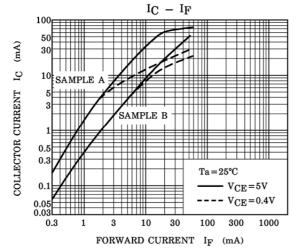


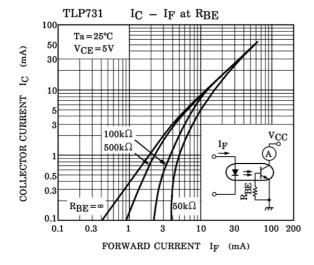


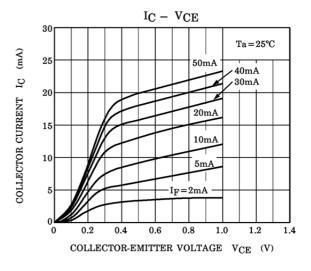


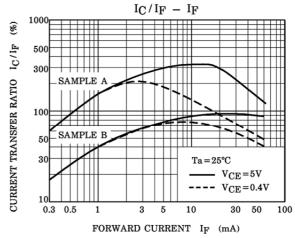


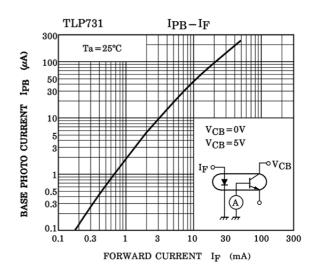




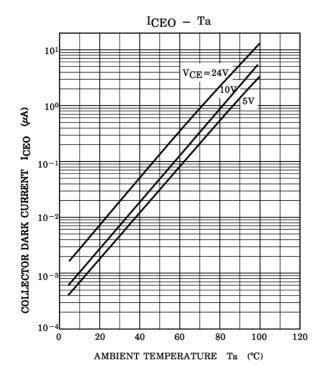


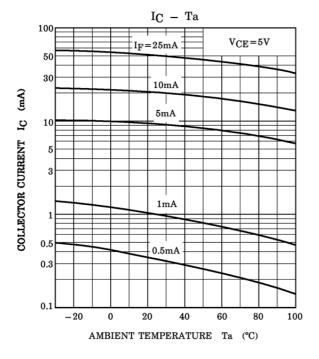


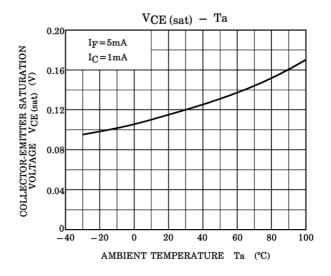


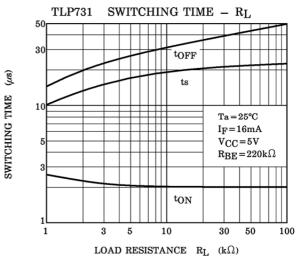


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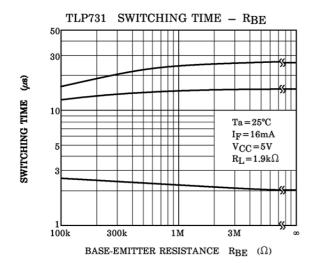


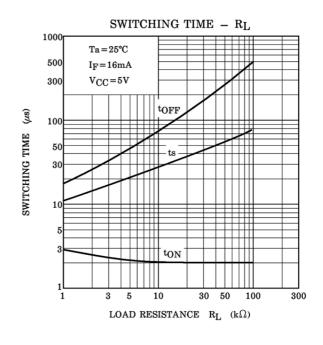






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